

ROITHNER LASERTECHNIK

A-1040 VIENNA, SCHOENBRUNNER STRASSE 7, AUSTRIA

TEL: +43 -1- 586 52 43-0 FAX: +43 -1- 586 52 43-44

e-mail: office@roithner-laser.com http://www.roithner-laser.com

RLT91500G TECHNICAL DATA



High Power Infrared Laserdiode

Structure: AlGaAs quantum well

Lasing wavelength: 915 nm typ., multimode

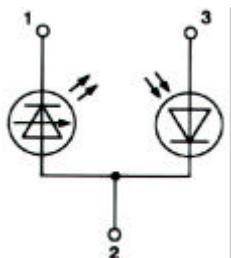
Optical power: 500 mW, 1 x 50 μm^2 aperture

Package: 9 mm

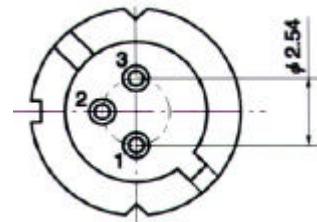
NOTE!
LASERDIODE
MUST BE COOLED!



PIN CONNECTION:



- 1) Laser diode cathode
- 2) Laser diode anode and photodiode cathode
- 3) Photodiode anode



Maximum Ratings ($T_c=25^\circ\text{C}$)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Optical Output Power	P_o	500	mW
LD Reverse Voltage	$V_{R(LD)}$	2	V
PD Reverse Voltage	$V_{R(PD)}$	30	V
Operating Temperature	T_c	-40 .. +50	$^\circ\text{C}$
Storage Temperature	T_{STG}	-70 .. +85	$^\circ\text{C}$

Optical-Electrical Characteristics ($T_c = 25^\circ\text{C}$)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Optical Output Power	P_o	CW		500		mW
Threshold Current	I_{th}	CW	80	100	120	mA
Operation Current	I_{op}	$P_o = 500 \text{ mW}$	500	600	700	mA
Operation Voltage	U_{op}	$P_o = 500 \text{ mW}$	1.6	1.8	2.0	V
Lasing Wavelength	λ_p	$P_o = 500 \text{ mW}$	910	915	920	nm
Spectral Width FWHM	$\Delta\lambda$	$P_o = 500 \text{ mW}$		10		nm
Beam Divergence	$\theta_{//}$	$P_o = 500 \text{ mW}$		8		$^\circ$
Beam Divergence	θ_\perp	$P_o = 500 \text{ mW}$	35	40	45	$^\circ$
Differential Efficiency	dP_o/dI_{op}	$P_o = 500 \text{ mW}$	0.8	1.0	1.2	mW/mA
Monitor Current	I_m	$P_o = 500 \text{ mW}$	150	350	800	μA